L Number	Hits	Search Text	DB	Time stamp
4	479	349/141.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/17 16:58
5	599	349/187.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/17 16:58
6	1893	(257/59,72).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/17 16:58
7	47987	gate adj insulat$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/17 16:58
8	1278573	semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/17 16:58
9	1374177	pattern$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/17 16:59
10	428809	mask photolithograph$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/17 16:59
11	2780	(gate adj insulat$3) same semiconductor same pattern$3 same (mask photolithograph$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/17 16:59
14	0	((bend splay) and chowdhury-tarifur$.xa.) and ((gate adj insulat$3) same semiconductor same pattern$3 same (mask photolithograph$6))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/17 16:59
12	22	(bend splay) and ((gate adj insulat$3) same semiconductor same pattern$3 same (mask photolithograph$6))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/17 17:00
13	13	chowdhury-tarifur$.xa. and ((gate adj insulat$3) same semiconductor same pattern$3 same (mask photolithograph$6))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/17 17:05
15	6932	cost near10 (mask photolithograph$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/17 17:06
16	225	(bend splay) and (cost near10 (mask photolithograph$6))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/17 17:06
17	15	chowdhury-tarifur$.xa. and (cost near10 (mask photolithograph$6))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/17 17:07

18	4	((bend splay) and chowdhury-tarifur$.xa.) and (cost near10 (mask photolithograph$6))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/17 17:07